LOW NOISE AMPLIFIER MODULE. 29 - 36 GHz



v05.0711

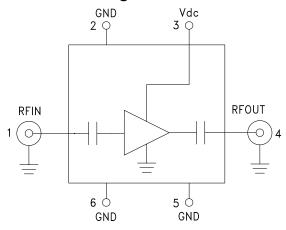


Typical Applications

The HMC-C027 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2.9 dB

Gain: 20 dB OIP3: 22 dBm

P1dB Output Power: +11 dBm 50 Ohm Matched Input/Output Hermetically Sealed Module

Field Replaceable 2.92 mm Connectors -55 °C to +85 °C Operating Temperature

General Description

The HMC-C027 is a GaAs MMIC pHEMT Low Noise Amplifier in a miniature, hermetic module which operates between 29 and 36 GHz. This high dynamic range amplifier module provides 20 dB of gain, 2.9 dB noise figure and up to +22 dBm of output IP3 from a single +3V supply. The wideband amplifier I/Os are internally matched to 50 Ohms and DC blocked for robust performance. The module features positive gain slope, and consistent noise figure and output power performance across its operating band.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +3V

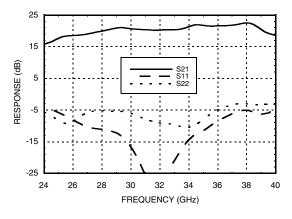
Parameter	Min.	Тур.	Max.	Units
Frequency Range		29 - 36		GHz
Gain	17	20		dB
Gain Variation Over Temperature		0.03	0.05	dB/ °C
Noise Figure		2.9	3.5	dB
Input Return Loss		14		dB
Output Return Loss		8		dB
Output Power for 1 dB Compression (P1dB)	8	11		dBm
Saturated Output Power (Psat)		13		dBm
Output Third Order Intercept (IP3)		22		dBm
Supply Current		80		mA



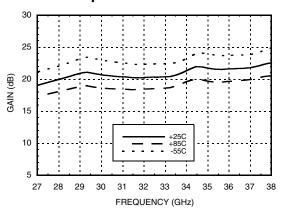


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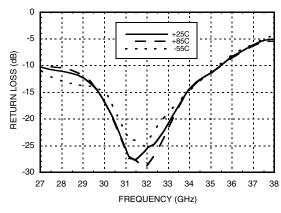
Broadband Gain & Return Loss



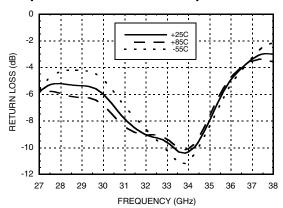
Gain vs. Temperature



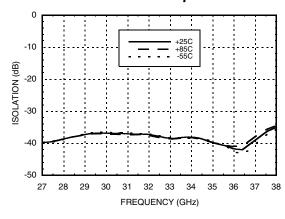
Input Return Loss vs. Temperature



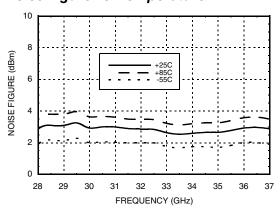
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature

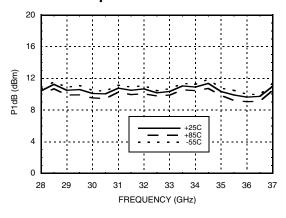




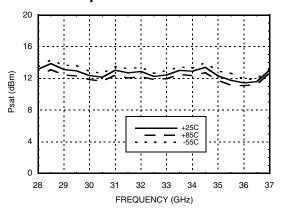


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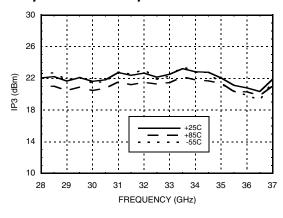
P1dB vs. Temperature



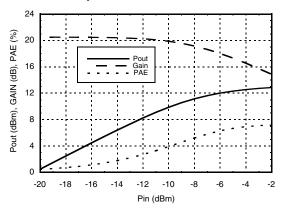
Psat vs. Temperature



Output IP3 vs. Temperature



Power Compression @ 32 GHz



Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+3.5 Vdc	
RF Input Power (RFIN)	+5 dBm	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	







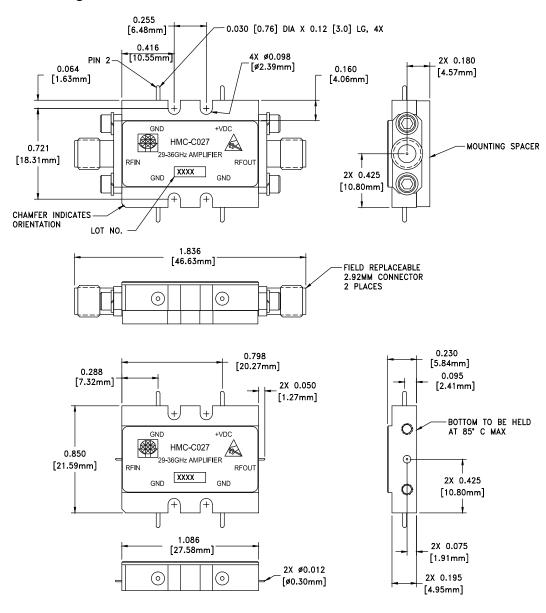
LOW NOISE AMPLIFIER MODULE, 29 - 36 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO— -
2, 5, 6	GND	One of these pins must be connected to power supply ground.	ĢGND <u></u>
3	Vdc	Power supply voltage for the amplifier. Includes zener diode for over voltage and negative voltage protection.	Vdc O
4	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ → RFOUT

LOW NOISE AMPLIFIER **MODULE, 29 - 36 GHz**

Outline Drawing



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

Package Information

Package Type	C-10	
Package Weight [1]	18.7 gms ^[2]	
Spacer Weight	3.3 gms ^[2]	

[1] Includes the connectors

[2] ±1 gms Tolerance

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4 TOLERANCES:
 - $4.1 .XX = \pm 0.02$
- $4.2.XXX = \pm 0.010$
- 5. FIELD REPLACEABLE 2.92mm CONNECTORS TENSOLITE 231CCSF OR EQUIVALENT



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AMPLIFIERS



ANALOGDEVICES

Notes:

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